

# Experimental signature of topologically protected surface states in a new-type centrosymmetric superconductor PdBi<sub>2</sub>

**J. Hu,<sup>1</sup> X. Wang,<sup>2</sup> S. Cooil,<sup>3</sup> R. K. Chellappan,<sup>1</sup> V. Bjelland,<sup>1</sup> F. Strand,<sup>1</sup> M. Hartl,<sup>1</sup> H. Røst,<sup>1</sup> C. Polley,<sup>4</sup> M. Bianchi,<sup>5</sup> J. Wells<sup>1,3,+</sup>**

<sup>1</sup> *Department of Physics, NTNU, Trondheim, Norway.*

<sup>2</sup> *Hunan University, Changsha, 410082, China..*

<sup>3</sup> *Semiconductor Physics, Department of Physics, University of Oslo (UiO), NO-0371 Oslo, Norway.*

<sup>4</sup> *MAX-lab, Lund University, Sweden.*

<sup>5</sup> *Department of Physics and Astronomy, Aarhus University, Denmark.*

Topological superconductors (TSCs) is a novel quantum phase of matter characterized by a fully gapped bulk state and gapless boundary states hosting exotic Majorana fermions. [1] The prospect of harboring vortex confined Majorana zero mode (MZM) for potential applications in quantum computation has attracted considerable experimental research interest. Recently, topologically protected surface states in a centrosymmetric layered superconductor,  $\beta$ -PdBi<sub>2</sub> was confirmed by Sakano et al,[2] and the corresponding possible spin triplet superconducting phases were examined and reported by Sun et al. [3]

In this work, we demonstrate how high-quality PdBi<sub>2</sub> samples growing layer-by-layer to the bulk phase by molecular beam epitaxy (MBE) and measured the atomic and electronic structures by scanning tunnelling microscopy (STM) and angle-resolved photoemission spectroscopy (ARPES) for comparison with first principles calculations. As compared to the  $\beta$ -PdBi<sub>2</sub> bulk single crystal hosting a topologically protected surface Dirac cone band with the binding energy of the Dirac point around 2.4 eV below Fermi level. Our results shift the Dirac point up to  $\sim 1.1$  eV is an important step towards realizing MBS in this robust system.

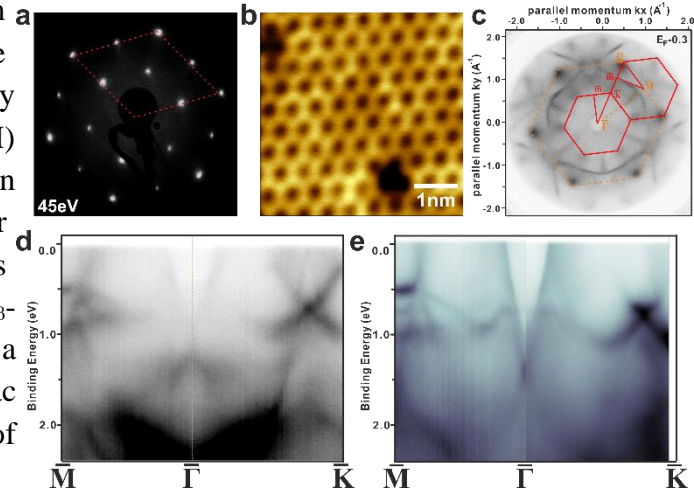


Figure 1. Epitaxial growth of PdBi<sub>2</sub> thin film(4 bilayer for (a-d) and 9 bilayer without Au background for (e)) on Au(111). **a**: (2x2)LEED pattern (45 eV). **b**: Atomic resolution STM image after Pd deposition. **c**: the constant energy contour cut at 0.3eV below Fermi level with the hexagonal surface Brillouin zones for Au(111)(yellow-dash) and PdBi<sub>2</sub> (red) thin film overlaid, respectively. **d-e**: band dispersions along Au(111) high-symmetry directions(yellow marks in (c)).

[1] J. Alicea, Rep. Prog. Phys. **75**, 076501(2012).

[2] M. Sakano *et al.*, Nat. Commun. **6**, 8595 (2015).

[3] Z. Sun et al., Nat. Commun. **6**, 6633 (2015).

+ Author for correspondence: j.w.wells@fys.uio.no